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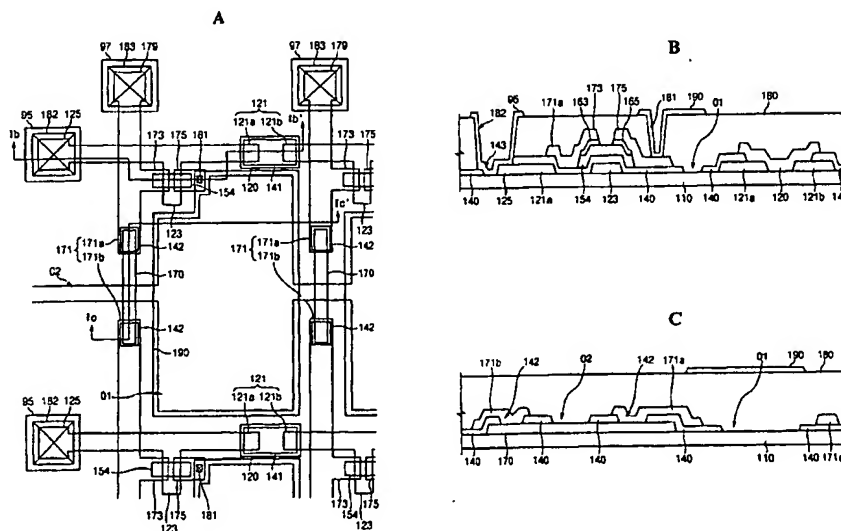
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 (71) **Applicant (for all designated States except US):** **SAM-SUNG ELECTRONICS CO., LTD.** [KR/KR]; 416, Maetan-dong, Yeongtong-gu, Suwon-si, Gyeonggi-do 442-742 (KR).
 (72) **Inventors; and**
 (75) **Inventors/Applicants (for US only):** **HONG, Mun-Pyo** [KR/KR]; Hansolmacul Cheonggu Apt. 112-205, Jeongja-dong, Bundang-ku, Seongnam-city, Kyungki-do 463-914 (KR), LEE, Yong-Uk [KR/KR]; Yaksu Apt. 309, Jung-dong, Jungwon-ku, Seongnam-city, Kyungki-do 462-170 (KR), KIM, Bo-Sung [KR/KR]; Songhyeon Villa 301, Bongcheon 6-dong, Kwanak-ku, Seoul 151-810 (KR).
 (74) **Agent:** **YOU ME PATENT & LAW FIRM;** Teheran Bldg., 825-33, Yoksam-dong, Kangnam-ku, Seoul 135-080 (KR).
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- (54) Title:** THIN FILM TRANSISTOR ARRAY PANEL AND METHOD MANUFACTURING THEREOF



- (57) **Abstract:** A thin film transistor array panel according to the present invention includes: an insulating substrate; a gate wire formed on the insulating substrate and including a plurality of gate portions and a gate connection connecting the gate portions; a data wire insulated from the gate wire and intersecting the gate wire; a thin film transistor connected to the gate wire and the data wire; and a pixel electrode connected to the thin film transistor.

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